

Pin	Description
1	input
4	+V <sub>Bias</sub>
5	+V <sub>B</sub>
9	output
2.3.7.8	common

### FEATURES >>

- Excellent linearity
- Extremely low noise
- Excellent return loss properties
- High gain
- High reliability

### DESCRIPTION

Hybrid amplifier module operating over a frequency range of 40 to 1218 MHz at a voltage supply of +24V(DC) ,employing GaAs MMIC.

### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNITS
G <sub>p</sub>	power gain	f=45 MHz	33.5	34.3	35	dB
I <sub>tot</sub>	total current consumption(DC)	V <sub>B</sub> =24V	290	300	320	mA

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System

SYMBOL	PARAMETER	MIN.	MAX.	UNITS
V <sub>i</sub>	RF input voltage (single tone)	-	70	dBmV
V <sub>vo</sub>	DC Supply over-voltage(5minutes)		30	V
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-30	+100	°C

## CHARACTERISTICS

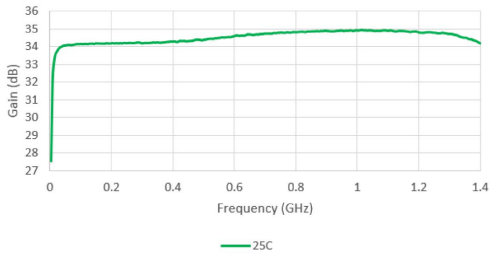
(Bandwidth 40 to 1218MHz;  $T_{mb}=25^{\circ}\text{C}$ ,  $V_B=24\text{V}$ ,  $Z_S=Z_L=75\Omega$ )

PART NUMBER			Egi12003424DG			
SYMBOL	PARAMETER	UNIT	MIN.	TYP.	MAX.	CONDITIONS
$G_P$	power gain	dB	33.5	34.3	35	f =45MHz
$G_P$	power gain	dB	-	34.6	-	f =1000MHz
$G_P$	power gain	dB	34	34.5	36	f =1218MHz
SL	slope cable equivalent	dB	0.5	1.0	1.5	f =40 to 1218 MHz
FL	flatness of frequency response	dB	-	-	0.8	f =45 to 1218 MHz
$S_{11}\&S_{22}$	Input&output return loss	dB	-	-	-18	f =45 to 640 MHz
$S_{11}\&S_{22}$	Input&output return loss	dB	-	-	-17	f =640 to 1000 MHz
$S_{11}\&S_{22}$	Input&output return loss	dB	-	-	-16	f =1000 to 1218 MHz
CTB	composite triple beat	dB	-	-65	-62	PAL:
CSO	composite second order distortion	dB	-	-65	-62	$V_o=45\text{dBmV}$ at 862MHz, flat, 99
XMOD	X modulation	dB	-	-62	-	Analog channels
CTB	composite triple beat	dB	-	-70	-	NTSC:
CSO	composite second order distortion	dB	-	-68	-	$V_o=47\text{dBmV}$ at 1200MHz, 0dB extrapolated tilt
CIN		dB	-	-64	-	79 analog channels plus 111QAM(-6dB offset)
F	noise figure	dB	-	5.0	5.5	f=45 to 1218 MHz
$I_{tot}$	total current consumption(DC)	mA	280	290	320	$V_B=+24\text{V}$

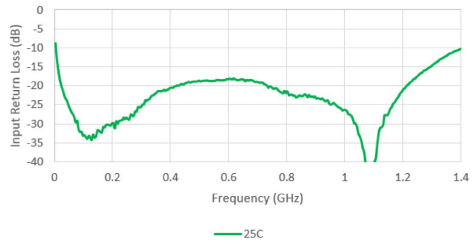
The module normally operates at  $V_B=24\text{V} (\pm 0.5)$ .

Performance data@24V

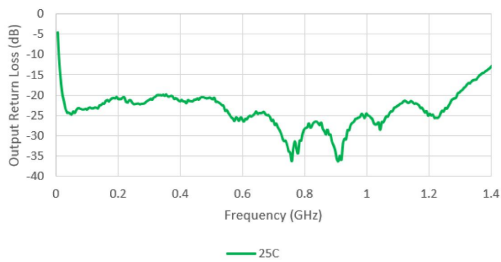
Gain vs Frequency



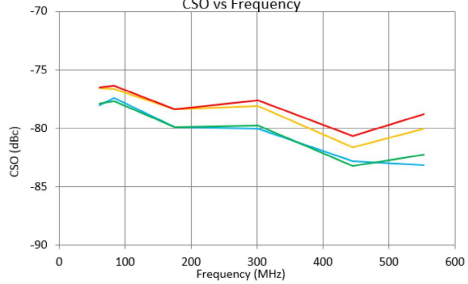
Input Return Loss vs Frequency



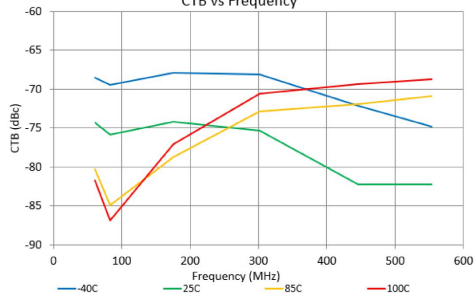
Output Return Loss vs Frequency



CSO vs Frequency



CTB vs Frequency



MODULE DIMENSIONS

